

(19) (KR)  
(12) (B1)

(51) 。 Int. Cl. <sup>7</sup> (45) 2003 03 29  
H05B 33/10 (11) 10 - 0378065  
(24) 2003 03 17

(21) 10 - 2001 - 0012032 (65) 2002 - 0072063  
(22) 2001 03 08 (43) 2002 09 14

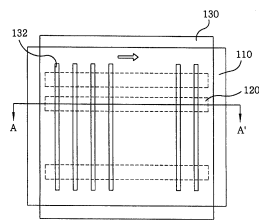
(73) 455 - 6  
(72) 1029 1 101 - 404  
353 - 1403  
108 - 1104  
11 - 1 522

(74)  
:

(54)

ITO(indium tin oxide) , (b) , (a)  
ITO , (c) ITO ,  
, (d) , (e) (c) (d) ,  
.

【図 5c】



- 1 ,
- 2 DBR ,
- 3 CCF ,
- 4 W - CFF ,
- 5a 5c ,
- 6a 6d 5c 5c A - A ' .

<

- 110 : 120 : ITO
- 130 : 132 :
- 140 :
- 160, 170, 180 : , ,

, .

가  
가 , , 가 (LCD), (PDP),  
(VFD), (Electroluminescence : EL)  
가 (Electroluminesc  
e : EL)  
(individual pixel type) , DBR  
CCF , W - CFF  
1 (10) (shadow mask) ( ) 가 가  
(R - , G - , B - OELD) (22, 24, 26)  
(22, 24, 26)  
가  
(10) - (ink - jet) 가  
가  
2 DBR (R), (G) (B)  
DBR(Distributed Brag Reflector) (32, 34, 36) (10)  
(Broad Band OELD) (42, 44, 46) DBR(32, 34, 36)  
3 CCF 가  
(10) ITO (52, 54, 56) (CCF : Color Convertin  
g Film) (52, 54, 56) (Blue - OELD) (62, 64,  
66) CCF  
LCD (CFF : Color Filter Film) 가 (cross - talk)  
가 가  
가  
4 LCD W - CFF (10)  
CFF(72, 74, 76) (White - OELD) (82, 84, 86)  
가

, ,  
 ,  
 : (a) ITO(in  
 dium tin oxide) ; (b) ITO  
 ; (c) ITO  
 ; (d)  
 ; (e)  
 (c) (d)  
 (c) ,  
 .

5  
 , 5a , 1000 ITO(indium tin oxide)가  
 0.7mm (110) , 가 ( (110)  
 ) ITO (120) t1 ITO (120)  
 . (+)  
 , 5b , (110) 150 - 200 $\mu$ m (130)  
 , 가 , 가 1  
 (110) ITO(120) (130)  $\mu$ m (132)  
 . (130) , t2 (132) , t3 (132)

$$t_2^2 < t_3 \quad t_2^2 \cdot 5$$

$$\begin{aligned}
 & , t_3 \\
 & , t_3 \quad t_2^2 \quad (t_2^2 \cdot 2) \\
 & , t_3 \quad t_2^2 \quad 5 \quad (t_2^2 \cdot 5) \\
 & , (t_2)
 \end{aligned}$$

, 5c 6a , ITO (120) (110) (130)  
 ( )  
 140) . , (140) AL:Li  
 (150) . , (150) 3000 , ( - ) .

6b ITO (120) (140) , (160)  
 (140)  
 (hall injection layer) (142), (hall transfer layer) (144),  
 (emission layer) (146), (electron layer) (148) .  
 (146) , (146) ,  
 (146) , , 6b  
 (R)

, ITO (120) (150) (+) ( - ) , ITO (120)  
 (150) 가 (140) (exc  
 iton) , 가 (ground state)  
 , ITO (120) .

, (160) , ITO (110) (130) t3  
 (160) , 5c (146)  
 (150) ,  
 (160) (170)  
 ( 6c ) .

, ITO (110) (130) t3  
 (170) , 5c (146)  
 (150) , ( )  
 170) (180) . , ,  
 (160, 170, 180) (130) t3  
 , , (200) .

, (130) ITO (110) (130) ITO (110)  
 , ( ) t3 ,  
 . PZT nm  
 PZT

(200) (144) ITO (120) (150) 가 (146)  
 (150)

가 .

(57)

1.

- (a) ITO(indium tin oxide) ;
- (b) ITO ;
- (c) ITO ;
- (d) ;
- (e) (c) (d) ,

2.

1 , (t3) ,

$t_2^2 < t_3$   $t_2^2 > t_3$

, t2 , t3 .

3.

1 2 , (hall i

njection layer), (hall transfer layer), (emission layer),

(electron layer) ,

(c) ,

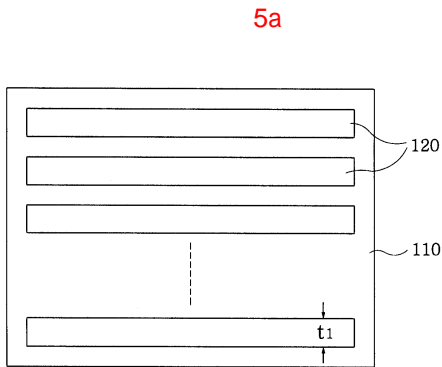
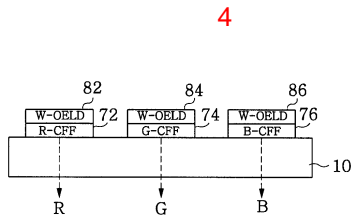
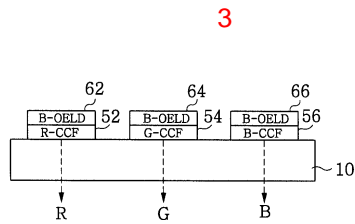
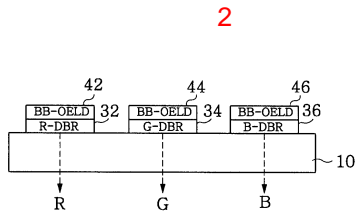
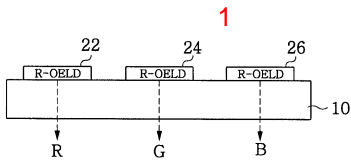
4.

1 , Al:Li .

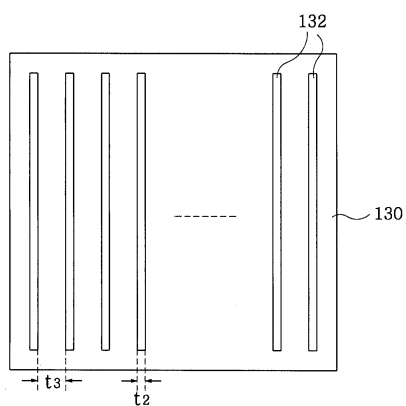
5.

1 ,

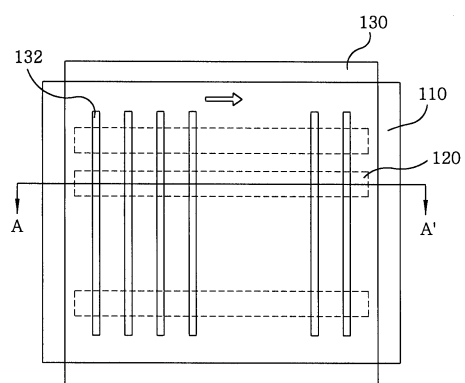
(t3)



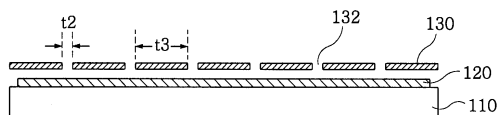
5b



5c

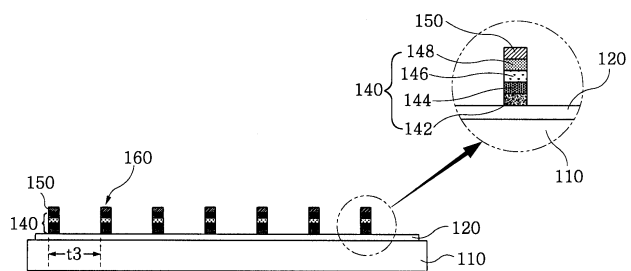


6a

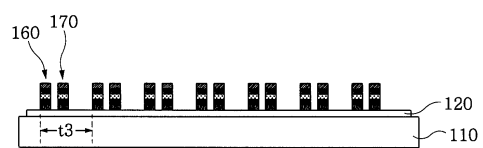




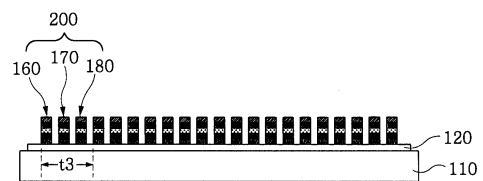
6b



6c



6d



专利名称(译)	使用单分子有机电致发光材料制造全色显示系统的方法		
公开(公告)号	<a href="#">KR100378065B1</a>	公开(公告)日	2003-03-29
申请号	KR1020010012032	申请日	2001-03-08
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IPC分类号	H05B33/10		
CPC分类号	H01L27/3211 H01L51/001 H01L51/0011 H01L51/56		
代理人(译)	张居正, KU SEONG		
其他公开文献	KR1020020072063A		
外部链接	<a href="#">Espacenet</a>		

#### 摘要(译)

本发明涉及一种方法，用于使用单分子有机电致发光材料制造的全色显示系统中，(a)玻璃图案电极(氧化铟锡)的基板上具有在纵向方向上的矩形形状的ITO屏幕，(b)除去在垂直通过形成多个细长狭缝，从金属板的金属掩模，和(c)具有在ITO电极的玻璃基板上的所述狭缝的金属制得的玻璃基板上的ITO jeongueukwa的方向上的金属部分(D)通过在单分子有机发光材料层上热层压金属混合物形成金属电极，以形成单色有机发光材料(E)在狭缝之间的区域中形成金属掩模，以便与形成的单色有机发光像素区域相邻定位并重复步骤(c)至(d)以形成用于全色显示器的有机电致发光器件。

- 1 -

